Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

0.990 inches

Overall Height:

0.250 inches

Overall Width:

0.400 inches

End Application:

B1b pacer bee

Mounting Facility Quantity:

1

Mounting Method:

Threaded stud

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

75.0 reverse voltage, instantaneous

Current Rating Per Characteristic:

20.00 amperes forward current, average absolute and 250.00 amperes forward current, average preset

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

Precious Material And Location:

Terminal lugs plated silver

Test Data Document:

00752-411259 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

2 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0